

Effective potentials for atom–atom interactions at low temperatures

Bo Gao¹

Shanghai Institute of Optics and Fine Mechanics, Chinese Academy of Sciences,
Shanghai 201800, China

and

Department of Physics and Astronomy, University of Toledo, Toledo, OH 43606, USA

E-mail: bgao@physics.utoledo.edu

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Abstract

We discuss the concept and design of effective atom–atom potentials that accurately describe any physical processes involving only states around the threshold. The existence of such potentials gives hope to a quantitative, and systematic, understanding of quantum few-atom and quantum many-atom systems at relatively low temperatures.

The concept of the model potential has played an important role in many branches of physics. Well known examples include the Morse potential [1] and the Lennard-Jones potential for molecular systems, and the hard-sphere (HS) potential and the delta function pseudopotential [2] widely used in many-body theories, including theories for Bose–Einstein condensates (BEC) [3].

There are many reasons why one uses a model potential instead of the ‘real’ potential. Here, we only emphasize that a problem can simply become unmanageable if the ‘real’ potential is used. For quantum systems, this statement quickly becomes true for three or more atoms. This explains, in part, that, despite its many limitations, it has proven difficult to go substantially beyond the Gross–Pitavskii theory for BEC that is based on the delta function pseudopotential [3].

Our goal here is to discuss the concept and design of model potentials that better reflect the reality of atom–atom interactions than either the HS potential or the delta function pseudopotential, yet are simple enough to allow for applications in quantum few-atom and quantum many-atom systems. Here, being ‘simple’, to a large extent, means being shallow, as it is the depth of a potential, which can be measured by the number of bound states it supports, that determines the complexity of the resulting quantum few-atom and quantum many-atom problems.

¹ <http://bgaowww.physics.utoledo.edu>

One of our key conclusions is the following. For N -atom states around the N -atom threshold (such as the BEC state [3]), or physical processes that involve only states around the threshold (such as the three-body recombination process [4, 5]), the interaction potential between a pair of atoms, no matter how deep it might be, can be replaced by an effective potential supporting only one or a few bound states. Furthermore, because different partial waves are described by the same effective potential, it can be used in precisely the same manner as any ‘real’ potential. In doing so, one reduces the complexity of the resulting quantum few-atom and quantum many-atom problems to a level comparable to that for He, a level that we are quickly learning to deal with [5, 6].

If one thinks of the delta function pseudopotential [2] as describing the atomic interaction at the longest length scale in the zero-energy limit, $2\pi/k$, the natural next step is the description of atomic interaction at the next, shorter, length scale. This scale is $\beta_n = (2\mu C_n/\hbar^2)^{1/(n-2)}$, which characterizes the long-range atomic interaction of the form of $-C_n/r^n$ (here $n > 2$ and μ is the reduced mass for a pair of atoms). The angular-momentum-insensitive quantum-defect theory (AQDT) [7, 8] provides a systematic description of atom–atom interactions at this scale and is the basis of our discussion.

Reference [7] focused on two-atom systems with $V(r) \rightarrow -C_6/r^6$, but the same concepts and formulation are readily generalized to any $n > 2$. In this general formulation, a two-atom system with an asymptotic potential of the form of $-C_n/r^n$ ($n > 2$) is described by a dimensionless K matrix $K^c(\epsilon, l)$ and a set of universal functions that are determined from the solutions of

$$\left[\frac{d^2}{dr^2} - \frac{l(l+1)}{r^2} + \frac{\beta_n^{n-2}}{r^n} + \bar{\epsilon} \right] u_{\epsilon l}(r) = 0, \quad (1)$$

where $\bar{\epsilon} \equiv 2\mu\epsilon/\hbar^2$. Specifically, $K^c(\epsilon, l)$ is defined by writing the wavefunction at large distances as a linear superposition of a pair of reference solutions of equation (1):

$$u_{\epsilon l}(r) = A_{\epsilon l} [f_{\epsilon l}^c(r) - K^c(\epsilon, l)g_{\epsilon l}^c(r)], \quad (2)$$

where f^c and g^c are purposely chosen to have the behaviour

$$f_{\epsilon l}^c \xrightarrow{r \ll \beta_n} (2/\pi)^{1/2} (r/\beta_n)^{n/4} \cos(y - \pi/4), \quad (3)$$

$$g_{\epsilon l}^c \xrightarrow{r \ll \beta_n} -(2/\pi)^{1/2} (r/\beta_n)^{n/4} \sin(y - \pi/4), \quad (4)$$

for all energies [7]. Here $y = [2/(n-2)](\beta_n/r)^{(n-2)/2}$.

AQDT asserts that $K^c(\epsilon, l)$ is approximately a constant that is independent of both ϵ and l , provided that β_n is greater than other, energy-independent, length scales present in the system [7]. For our purposes here, the most important conclusion of AQDT is the following. *To the extent of $K^c(\epsilon, l)$ being energy and angular momentum independent, potentials with the same type of long-range behaviour (namely the same n) and the same K^c have, on a scaled energy basis, the same bound spectra and scattering properties around the threshold* [7]. Here the bound spectra and scattering properties include all angular momentum states for which K^c remains approximately l -independent. A similar idea can also be found in the work of Flambaum *et al* [9], even though it focused mostly on the s wave.

Ignoring scaling relations implied by this statement, which will be discussed elsewhere [10], AQDT gives the following simple prescription for designing an effective potential that has the same physical properties around the threshold as the system of interest. First, choose a model potential. The only restriction is that it should have the right asymptotic behaviour. Second, adjust the short range parameters of the model potential so that

$$K_{\text{mod}}^c(0, l) = K^c(0, l) \quad (5)$$

for one particular l . These two conditions do not uniquely determine an effective potential. Another auxiliary condition, which gives a convenient characterization of the depth of a potential, is the number of bound levels supported by a model potential for a particular l , N_l . For classes of model potentials discussed below, these conditions uniquely determine a model potential.

We stress here two classes of model potentials for which $K^c(0, l)$, and the number of bound levels for each l , N_l , can be found analytically. One class is of the type of a HS with an attractive tail:

$$V_{\text{HST}}(r) = \begin{cases} \infty, & r \leq r_0 \\ -C_n/r^n, & r > r_0, \end{cases} \quad (6)$$

which will be denoted by HST. The other class is of the type of Lennard-Jones (LJ) ($n, 2n-2$):

$$V_{\text{LJ}n}(r) = -C_n/r^n + C_{2n-2}/r^{2n-2}, \quad (7)$$

which will be denoted by LJn. In particular, this potential corresponds to a LJ(6, 10) potential for $n = 6$.

For HST potentials, it is not difficult to show that the K^c parameter at zero energy is given by [10]

$$K_{\text{HST}}^c(0, l) = -\frac{J_{\nu_0}(y_0) \cos(\pi \nu_0/2) - Y_{\nu_0}(y_0) \sin(\pi \nu_0/2)}{J_{\nu_0}(y_0) \sin(\pi \nu_0/2) + Y_{\nu_0}(y_0) \cos(\pi \nu_0/2)}, \quad (8)$$

where $\nu_0 = (2l+1)/(n-2)$, J and Y are the Bessel functions [11] and $y_0 = [2/(n-2)](\beta_n/r_0)^{(n-2)/2}$. The number of bound levels for angular momentum l is given by

$$N_{\text{HST}}(l) = \begin{cases} m, & j_{\nu_0, m} \leq y_0 < j_{\nu_0, m+1} \\ 0, & y_0 < j_{\nu_0, 1}, \end{cases} \quad (9)$$

where $j_{\nu_0, m}$ ($m \geq 1$) is the m th zero of the Bessel function $J_{\nu_0}(x)$ [11].

For LJn potentials, the following results can be derived with the help of a local scaling transformation [10]:

$$K_{\text{LJ}n}^c(0, l) = \tan(\pi \nu_0/2)[1 + h_l(z_0)][1 - h_l(z_0)]^{-1}, \quad (10)$$

where $z_0 = (\beta_n/\beta_{2n-2})^{n-2}/[2(n-2)]$,

$$h_l(z_0) = z_0^{\nu_0} \frac{\sin \pi(z_0 + 1/2 - \nu_0/2)\Gamma(z_0 + 1/2 - \nu_0/2)}{\sin \pi(z_0 + 1/2 + \nu_0/2)\Gamma(z_0 + 1/2 + \nu_0/2)} \quad (11)$$

and $\nu_0 = (2l+1)/(n-2)$. The number of bound levels for any l is given by

$$N_{\text{LJ}n}(l) = \begin{cases} \left[z_0 + \frac{1}{2} - \frac{\nu_0}{2} \right], & z_0 \geq (\nu_0 + 1)/2 \\ 0, & z_0 < (\nu_0 + 1)/2, \end{cases} \quad (12)$$

where $[x]$ means the greatest integer less than or equal to x . We note that scattering lengths, which are much more restrictive concepts [8, 12], can be derived from $K^c(0, l)$. For example, the s wave scattering length, which is defined only for $n > 3$, can be obtained from $K^c(0, l = 0)$:

$$a_{l=0}/\beta_n = \left[b^{2b} \frac{\Gamma(1-b)}{\Gamma(1+b)} \right] \frac{K^c(0, 0) + \tan(\pi b/2)}{K^c(0, 0) - \tan(\pi b/2)}, \quad (13)$$

where $b = 1/(n-2)$. If a semiclassical expression is used for $K^c(0, 0)$, this result for the scattering length reduces to that of Gribakin and Flambaum [13]. A similar result for the scattering length has also been derived by Szmytkowski [14].

Table 1. Selected data for effective potentials designed for the triplet state of a ^{23}Na dimer. All potentials have $C_6 = 1556$ au [17] and $K^c(0, l = 0) = 13.57$. $N_{l=0}$ is the number of s wave bound levels supported by the potential. D_e is the depth of a potential. It is a derived parameter presented for discussion.

$N_{l=0}$	LJ(6, 10)		HST	
	C_{10} (au)	D_e (mK)	r_0 (au)	D_e (mK)
1	1.65080×10^9	83.5879	32.2715	434.985
2	4.05415×10^8	686.809	24.0025	2569.51
4	1.00245×10^8	5585.89	17.4332	17503.6
16	6.21105×10^6	362192	8.89948	989000

From these results, the HST and LJ n types of potentials can be readily designed according to equation (5) to have the desired $K^c(0, l)$ and the desired N_l . Table 1 gives a selected set of designs for the triplet state of a ^{23}Na dimer. Here the potentials are designed to have $K^c(0, l = 0) = 13.57$, which is found numerically using the latest potential for a sodium dimer [15, 16]. From equation (13), this corresponds to an s wave scattering length of 64.57 au. The number of bound s wave levels supported by this ‘real’ potential is found numerically to be 16.

Figure 1 shows the comparison of s and d wave partial cross sections of effective LJ(6, 10) and effective HST potentials, both designed to support 16 s wave bound levels and have a $K^c(0, l = 0) = 13.57$, with the Na–Na partial cross sections computed from the ‘real’ potential [15, 16]. The results are hardly distinguishable over a wide range of energies. In comparison, the hard-sphere (HS) potential fails quickly away from the threshold for the s wave and gives completely wrong results for the d wave.

This result confirms the concept of effective potential based on AQDT. For our purposes here, however, what is more important is how shallow the effective potentials can be while still maintaining a good description of low-energy characteristics of a real system. Figure 2 shows the comparison of s and d wave partial cross sections of an effective LJ(6, 10) potential, in this case designed to support only a single s wave bound state, with the ‘real’ Na–Na results². The agreements remain excellent.

Figure 3 shows similar results for a HST potential. In this case, the HST potential that supports only a single s wave bound state does not do as well near the d wave shape resonance because a shallow HST potential does not maintain the l independence of K^c as well as a shallow LJ(6,10) potential. Even so, the result quickly improves, monotonically, as the number of bound levels supported by HST increases. By $N_{l=0} = 4$, a good agreement is achieved. The s wave result for HST supporting a single s wave bound state remains excellent because the energy independence of K^c is maintained fairly well even for such a shallow potential.

The robustness of these designs is not limited to the description of scattering properties, it also applies to the energies of bound states that are close to the dissociation threshold and to the wavefunctions. For example, for effective potentials supporting 4 s wave bound levels, the HST gives a binding energy of 0.2027 GHz (9.730 mK) for the least-bound s state, while the LJ(6, 10) gives 0.2003 GHz (9.613 mK). Both are in good agreement with the result for the ‘real’ potential, which gives 0.2044 GHz (9.811 mK) (see footnote 2). Figure 4 shows that, for effective potentials supporting 4 s wave bound levels, the wavefunctions are well represented down to $r = 20$ au, covering basically all regions of space in which there is an appreciable amplitude.

² All results for Na dimers are computed from the potential of [15, 16].

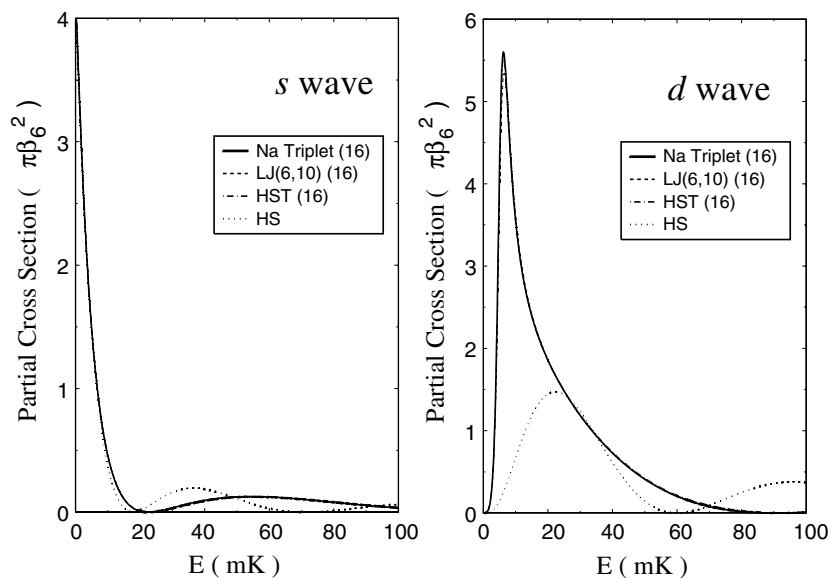


Figure 1. Comparison of s and d wave partial cross sections of effective LJ(6, 10) and HST potentials, both designed to support 16 s wave bound levels and have $K^c(0, l = 0) = 13.57$, with the ‘real’ Na–Na partial cross sections (see footnote 2). The number in parentheses represents the number of s wave bound levels supported by a potential. Results for a HS potential are also shown for comparison.

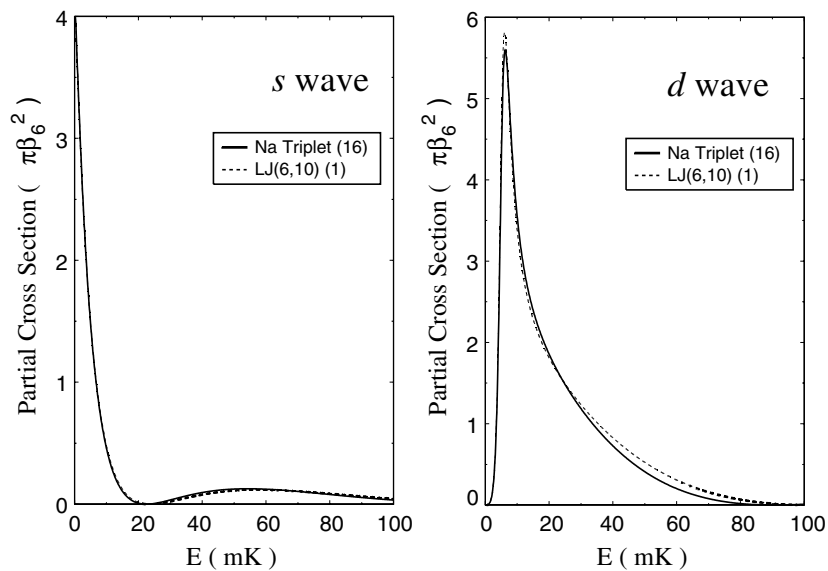


Figure 2. Comparison of s and d wave partial cross sections for an effective LJ(6, 10) potential, designed to support a single s wave bound level, with the ‘real’ Na–Na cross sections (see footnote 2).

We stress that, while only the results for sodium are presented here, they are used to illustrate much more general concepts. As the number of bound levels supported by an effective potential increases, all physical properties of states around the threshold converge

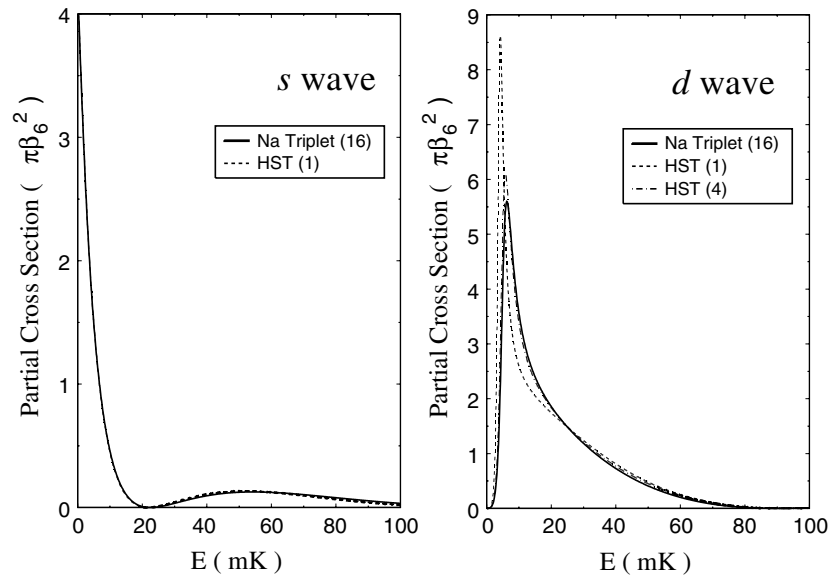


Figure 3. Comparison of s and d wave partial cross sections for effective HST potentials, designed to support 1 and 4 s wave bound levels, with the 'real' Na–Na cross sections (see footnote 2).

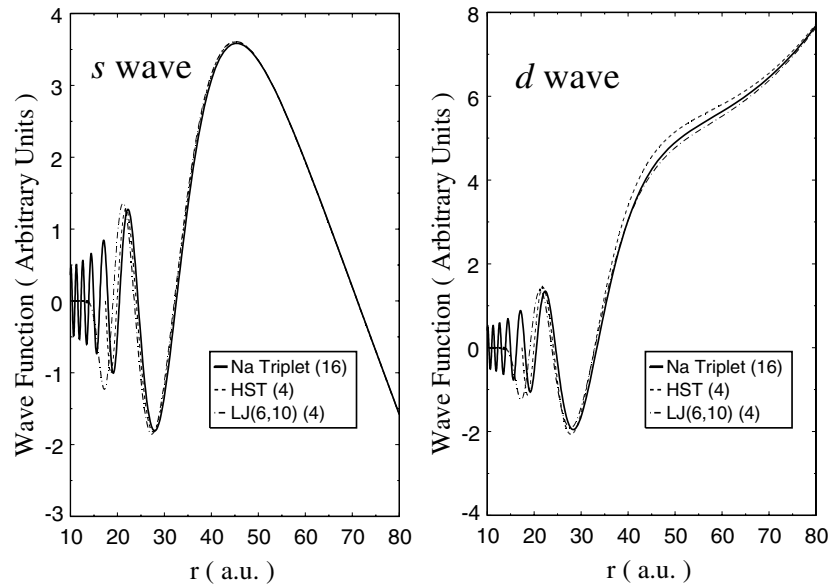


Figure 4. Zero-energy wavefunctions of effective potentials with 4 s wave bound levels compared with the 'real' Na–Na wavefunctions (see footnote 2).

to the same results (see figures 1–4). This is the *shape independence at length scale β_n* . The converged results, properly scaled, represent a set of universal properties shared by all quantum systems with the same type of long-range potential and characterized by the same l -independent constant $K^c = \lim_{\beta_x/\beta_n \rightarrow 0} K^c(0, l)$ [7], where β_x represents the next shorter length scale present in the system. The examples presented here, figures 2–4, show how quickly this set of universal properties are approached as one increases the number of bound levels

supported by an effective potential. This quick convergence is due to the fact that deviations from the universal behaviour depend on a high power of β_x/β_n [10]. Other quantum systems differ from Na primarily in K^c [7], which does not affect this rapid convergence.

Note that we did not make any distinction between two-atom and N -atom quantum systems in the statements above, because the same applies to a N -atom system. A short argument is simply that diffuse states, in which atoms are mostly at large distances relative to each other, only couple coherently to other diffuse states. A longer argument can proceed as follows. The correct $K^c(0, 0)$, and therefore $a_{l=0}$, ensures the correct results at the mean-field level [3]. The correct two-atom wavefunction ensures the correct two-atom correlation. It also ensures the correct three-atom correlation, as follows. Think of a three-atom as a two-atom perturbed by another. Frank–Condon considerations tell us that only two-atom states around the threshold are significantly coupled. This means by having the correct two-atom wavefunctions around the threshold, one has also the correct three-atom correlation around the threshold.

To illustrate the savings of computer resources as a result of using an effective potential, consider the problem of N interacting atoms in a symmetric trap of frequency ω . If a real potential is used, the fact that we need to represent the length scale of $(2\mu D_e/\hbar^2)^{-1/2}$ means we need roughly $D_e/\hbar\omega$ number of harmonic oscillator states for each atom, for a total of $(D_e/\hbar\omega)^N$ number of states (ignoring statistics). If an effective potential is used, the corresponding number is $(D_{e,\text{eff}}/\hbar\omega)^N$. Thus the saving in the size of the basis set is characterized by the factor $(D_{e,\text{eff}}/D_e)^N$. For the triplet state of Na, $D_{e,\text{eff}}/D_e$ is of the order of 10^{-3} if an effective potential with 2 s wave bound levels is used (see table 1). This corresponds to a saving in the size of basis set of 10^9 -fold just for a three-atom problem. Even greater savings are achieved for deeper potentials or for more atoms. From another angle, for effective potentials with $N_{l=0} \sim 1$, all length scales shorter than β_n have effectively been eliminated. It is this elimination of short length scales that makes a complex problem more manageable.

On the other hand, if a good description over an even wider range of energies around the threshold is desired, the same methodology can be carried to scales shorter than β_n (e.g. β_8 for atoms with a $-C_6/r^6$ long-range interaction and a $-C_8/r^8$ correction) [10]. However, because the ratio β_8/β_6 is different for different systems, the results become dependent upon one more system-specific parameter. At this stage, going to shorter length scales seems useful only in specialized two-atom applications [10, 18]. We also point out that it is around the threshold that the quantum effects are most important [19].

In conclusion, we have established the concept and design of effective potentials describing atomic interactions at the length scale of β_n . It is the scale that one has to deal with in studying quantum few-atom [4] and quantum many-atom systems [3] at finite temperature, of high density or under strong confinement. We expect the method presented to play a role in our understanding of some of the more complex systems and processes at low temperatures, such as the three-body recombination process [4, 5], excited cluster states [6] and quantum liquids [3]. In all cases, one can look for, and verify, universal properties at the scale of β_n , by comparing results from different designs, such as HST and LJn, and by checking convergences as one relaxes an effective potential towards more bound levels. Applications to BEC with a large gaseous parameter $\rho a_{l=0}^3$ (ρ is the number density) and BEC with negative scattering length will be presented elsewhere.

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